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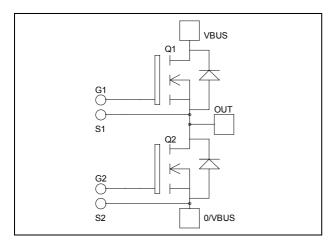






Phase leg MOSFET Power Module

$$\begin{split} V_{DSS} &= 1000V \\ R_{DSon} &= 90 m\Omega \ typ \ @ \ Tj = 25^{\circ}C \\ I_D &= 78A \ @ \ Tc = 25^{\circ}C \end{split}$$



O/VBUS

Application

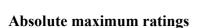
- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Power MOS 7[®] FREDFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Fast intrinsic reverse diode
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant



Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		1000	V
I_D	Continuous Drain Current	$T_c = 25$ °C	78	
1D	Continuous Diam Current	$T_c = 80$ °C	59	A
I_{DM}	Pulsed Drain current		312	
V_{GS}	Gate - Source Voltage		±30	V
R_{DSon}	Drain - Source ON Resistance		105	mΩ
P_D	Maximum Power Dissipation	$T_c = 25$ °C	1250	W
I_{AR}	Avalanche current (repetitive and non repetitive)		25	A
E_{AR}	Repetitive Avalanche Energy		50	mJ
E_{AS}	Single Pulse Avalanche Energy		3000	1113

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25^{\circ}$ C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 1000V$	$T_j = 25^{\circ}C$			400	μΑ
		$V_{GS} = 0V, V_{DS} = 800V$	$T_j = 125$ °C			2000	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 39A$			90	105	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 10$ mA		3		5	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$				±250	nA

Dynamic Characteristics

•	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		20.7		
C_{oss}	Output Capacitance	$V_{\rm DS} = 25V$		3.5		nF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		0.64		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		744		
Q_{gs}	Gate – Source Charge	$V_{Bus} = 500V$		96		пC
Q_{gd}	Gate – Drain Charge	$I_D = 78A$		488		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		18		
T_{r}	Rise Time	$\begin{split} V_{GS} &= 15 V \\ V_{Bus} &= 670 V \\ I_D &= 78 A \\ R_G &= 1.2 \Omega \end{split}$		12		ns
$T_{d(off)}$	Turn-off Delay Time			155		
T_{f}	Fall Time			40		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		3.6		I
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 670V$ $I_D = 78A, R_G = 1.2\Omega$		2.5		mJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		5.7		_
E _{off}	Turn-off Switching Energy	$I_{D} = 78A, R_{G} = 1.2\Omega$		3.1		mJ

Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I_S	Continuous Source current		$Tc = 25^{\circ}C$			78	A
	(Body diode)		$Tc = 80^{\circ}C$			59	Λ
V_{SD}	Diode Forward Voltage	$V_{GS} = 0V, I_S = -78A$	<u>.</u>			1.3	V
dv/dt	Peak Diode Recovery •					18	V/ns
t _{rr}	Reverse Recovery Time	Y 70 A	$T_j = 25^{\circ}C$			320	ns
	reverse receivery Time	$I_S = -78A$ $V_R = 670V$	$T_j = 125$ °C			650	113
Q _{rr}	Reverse Recovery Charge	$di_{S}/dt = 400A/\mu s$	$T_j = 25^{\circ}C$		14.4		μC
			$T_{j} = 125^{\circ}C$		38.9		

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

 $I_S \leq \text{- 78A} \qquad \text{di/dt} \leq 700 \text{A/} \mu \text{s} \qquad V_R \leq V_{DSS} \qquad T_j \leq 150 ^{\circ} \text{C}$

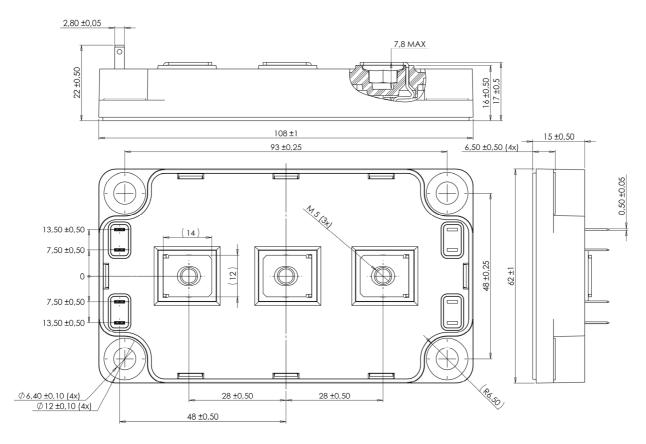
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Thermal and package characteristics

Symbol	Characteristic		Min	Тур	Max	Unit	
R_{thJC}	Junction to Case Thermal Resistance					0.1	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range		-40		150	°C	
T_{STG}	Storage Temperature Range			-40			125
$T_{\rm C}$	Operating Case Temperature			-40			100
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	11.111
Wt	Package Weight					300	g

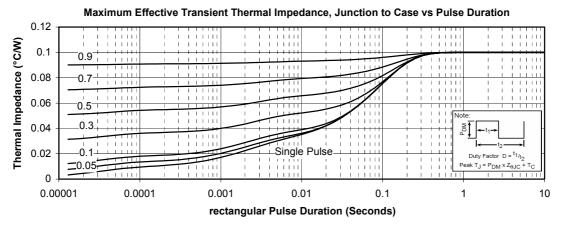
SP6 Package outline (dimensions in mm)

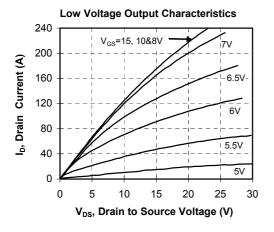


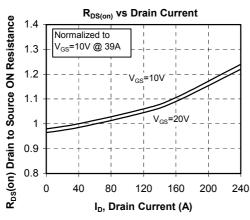
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

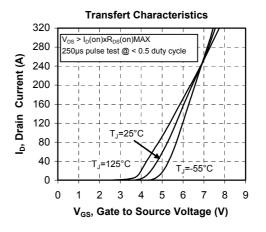


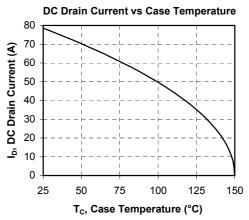
Typical Performance Curve



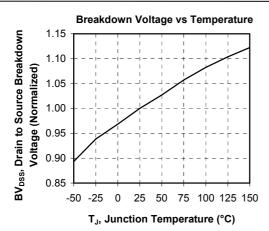


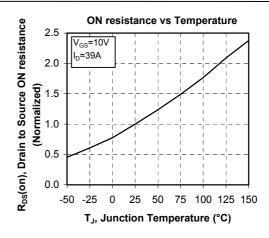


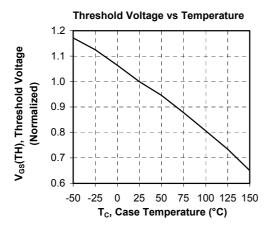


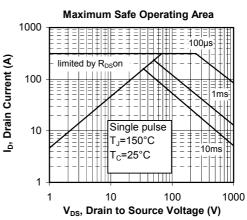


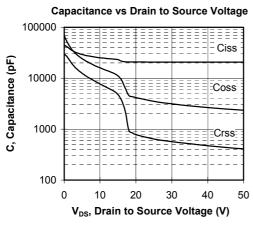


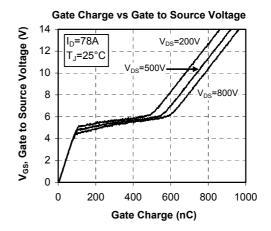




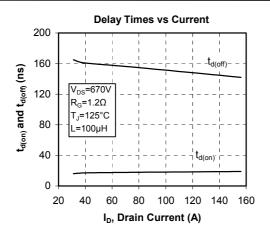


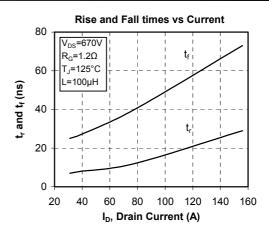


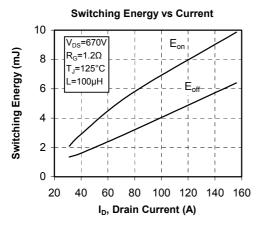


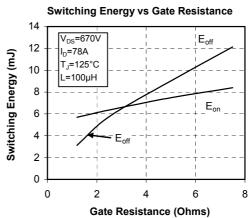


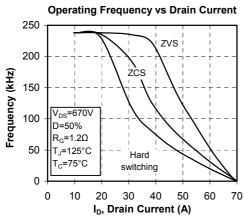


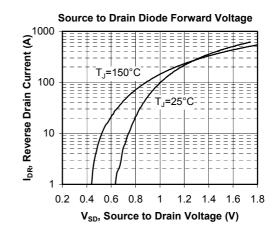














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